

# **TPM23513B Driver EVM User's Guide**



# DESCRIPTIONS

The TPM23513B driver is a singlechannel isolated gate driver for IGBTs, MOSFETs, and SiC MOSFETs. Its input is optocoupler compatible with the industrial standard widebody WSOP6 package. The driver is capable of sourcing 4.5 A and sinking 5 A of current. The output stage can withstand high voltages up to 40 V, making it suitable for the latest generation of IGBT and SiC-based applications.

### **Key Features**

- Single-Channel Isolated Gate Driver with Optocoupler-Compatible Input
- 4.5-A Source/5-A Sink Peak Output Current with Rail to-Rail Output
- 10-V to 40-V Output Driver Supply Voltage
- 5.7-V Reverse Polarity Voltage Handling Capability on Input Stage
- 5-kVRMS Reinforced Isolation Rating
- ±150-kV/µs Common-Mode Transient Immunity (CMTI)
- Industrial Standard Wide-Body WSOP6 Package
- Operating Ambient Temperature -40°C to +125°C

# **APPLICATIONS**

- Industrial Motor-Control Drives
- Industrial Power Supplies, UPS
- Solar Inverters
- Induction Heating

#### **Revision History**

Revise Date	Version	Reason/Issue
2024-11-22	A0	First Issue



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# **1. Electrical Specifications**

A summary of the TPM23513B EVM performance specifications is provided in Table.1. Specifications are given for VCC2=15V, unless otherwise specified. The ambient temperature is 25°C for all measurements, unless otherwise noted.

PARAMETER	DESCRIPTION	MIN	Туре	Max	UNITS
VDD	Primary-side power supply	4.5		5.5	V
VCC	Secondary-side power supply	10	15	40	V

#### Table.1 TPM23513B EVM Performance Specification

# 2. EVM Documentation

# 2.1 Schematic



Fig. 1 TPM23513B EVM Schematic



# 2.2 Bill of Material

Designator	Qty	Value	Description	Package	Part No.	MFR
C1	1	100nF ±10%	CAP CREM, 2.2F, 50V X5R	0603	CC0603KRX	YAGEO
		50V			7R9BB104	
C4, C7	1	2.2uF ±10%	CAP CREM, 2.2F, 50V X5R	0805	CL21A225KB	SAMSUNG
		50V			QNNNE	
C8, C11	2	22pF ±5%	CAP CREM, 22pF, 50V C0G	0603	CL10C220JB	SAMSUNG
		50V			8NNNC	
C6	2	100nF ±10%	CAP CREM, 100nF, 50V X7R	0805	CC0805KRX	YAGEO
		50V			7R9BB104	
C9	1	100pF ±5%	CAP CREM, 100pF, 50V C0G	0603	CL10C101JB	SAMSUNG
		50V			8NNNC	
C14	1	1nF ±10%	CAP CREM, 10nF, 50V X7R	0805	CL21B102KB	SAMSUNG
		50V			CNNNC	
C15	1	180nF ±10%	CAP CREM, 180nF, 50V X7R	0805	TCC0805X7	CCTC
		50V			R184K500DT	
R4, R6	2	137Ω ±1%	Res,0.125W,0805	0805	CR0805F813	LIZ
		125mW			70G	
R7, R10	1	0Ω 125mW	Res,0.125W,0805	0805	CRCW08050	VISHAY
					000Z0ECC	
R12	1	50mΩ ±1%	Res,1%,0.125W,0805	0805	WSL0805R0	VISHAY
		125mW			500FEA	
U1	1	SN74LVC2G	Dual Schmitt-Trigger Buffer	SOT-23-6	SN74LVC2G	ТІ
		17DBVR			17DBVR	
U2	1	TPM23513B	Opto-Compatible 1CH	WSOP-6	TPM23513B-	3PEAK
			Isolated Gate Driver		SOER	

#### Table.2 TPM23513B EVM Bill of Materials

# 2.3 PCB Layout



Fig. 2 TPM23513B EVM PCB Layout



# 3. Test Setup and Procedure

# 3.1 Test Setup

The TPM23513 EVM is provided with input/output connectors and test points as shown in Table.3.

Designator	Description		
J1	+10 V–40 V Output-Side Supply		
J2	+5 V Buffer Supply		
J3	+5 V Buffer Supply		
J4	Anode Buffer Jumper		
J5	Anode Buffer Input		
J6	Cathode Buffer Input		
J7	Cathode Buffer Jumper		
J8	Cathode Resistor to GND Jumper		
19	VOUT Pin to 1nF Load Jumper		
J10	VOUT Pin to $180nF+50\Omega$ Load Jumper		

#### Table.3 TPM23513B EVM Connections

The recommended connections to evaluate TPM23513B-EVM are shown in Fig.3.



Fig. 3 EVM Test Setup

# 3.2 Test Equipment

Table. 4 lists the equipment used by 3PEAK. Other instruments capable of supporting the required voltage, current, and power levels for this EVM test may also be used.



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Table.4 Test Equipments Used by 3PEAK				
Instruments	Model	Vender		
DC Source	E36313A	Keysight		
Waveform Generator	33600A	Keysight		
Oscilloscope	MXR108A	Keysight		

# 3.3 Test Procedure

- Set up the EVM as described in Fig.3.
- Set the waveform generator to 5V, 20kHz, 50%.
- Set the primary power supply to 5V and the secondary power supply to 10V~40V.
- Oscilloscope is used to capture waveforms.

# 4. Test Results and Performance Evaluation

# 4.1 Example Input and Output Waveforms

Below shows the input and output waveforms of the EVM. The orange, red, and blue waveforms in the diagram represent the input voltage, input current, and output voltage of the TPM23513B, respectively.



# 4.2 Output Rising Waveforms

Below shows the output rising waveforms of the EVM. As shown in Fig.5, the output rise time is nearly 12ns. As shown in Fig.6, the propagation delay from input to output is nearly 63ns.



#### 4.2.1 Output Rise Time







# 4.3 Output Falling Waveforms

Below shows the output falling waveforms of the EVM. As shown in Fig.7, the output fall time is nearly 7.6ns. As shown in Fig.8, the propagation delay from input to output is nearly 60ns.

4.3.1 Output Fall Time





#### 4.3.2 Propagation Delay



## 4.4 Peak Output Current Measurement Using 180nF&50mΩ Load

The output can be configured to measure the peak output current by shifting the jumper from J9 to J10. This jumper connects a 180 nF load capacitor and a 50 m $\Omega$  resistor in series (C15 and R12), allowing the output current to be indirectly measured by monitoring the voltage across R12. The output current is then determined by dividing the voltage across R12 by its resistance value.

#### 4.4.1 Peak Source Output Current Measurement

The orange and green waveforms in the diagram represent the input voltage and the voltage across R12, respectively. The overshoot observed in the voltage across R12 is attributed to the parasitic inductance of R12. The peak source output current is calculated by dividing the voltage across R12 by its resistance value: 258.8mV/50m $\Omega$ =5.18A.





#### 4.4.2 Peak Sink Output Current Measurement

The peak sink output current is calculated by dividing the voltage across R12 by its resistance value:  $462.7mV/50m\Omega = 9.254A$ .





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